

IPW60R041C6

IPW60R041C6 Information

www.hoj.com	Part Number	IPW60R041C6	
	Manufacturer	Infineon Technologies	
	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
	Description	MOSFET N-CH 600V 77.5A TO 247-3	
	Package	TO-247-3	
~		For the pricing/inventory/lead time, please contact us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPW60R041C6 Specifications

Manufacturer Part Number	IPW60R041C6
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	CoolMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	77.5A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	3.5V @ 2.96mA
Gate Charge (Qg) (Max) @ Vgs	290nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	6530pF @ 10V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	481W (Tc)
Rds On (Max) @ Id, Vgs	41 mOhm @ 44.4A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO247-3
Package / Case	TO-247-3
	Report errors?

IPW60R041C6 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPW60R041C6 Payment Methods



IPW60R041C6 Shipping Methods



If you have any question about IPW60R041C6, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com